

80V N-Channel MOSFET

General Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

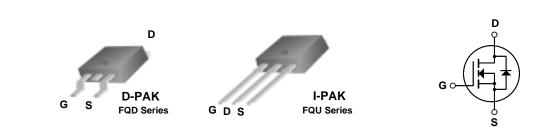
This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for low voltage applications such as automotive, high efficiency switching for DC/DC converters, and DC motor control.

Features

19.6A, 80V, R_{DS(on)} = 0.06Ω @V_{GS} = 10 V

August 2000

- Low gate charge (typical 19 nC)
- Low Crss (typical 50 pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability



Absolute Maximum Ratings T_c = 25°C unless otherwise noted

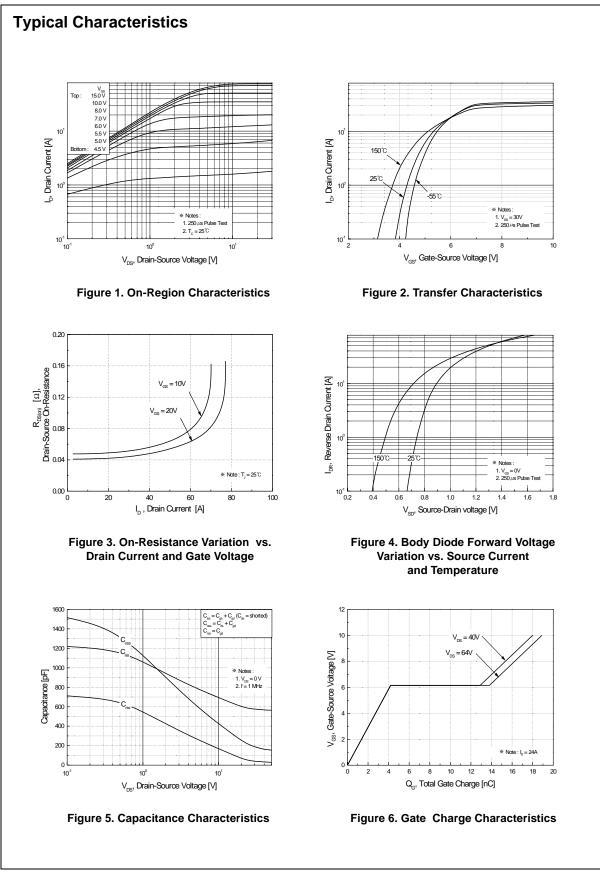
Symbol	Parameter		FQD24N08 / FQU24N08	Units	
V _{DSS}	Drain-Source Voltage		80	V	
I _D	Drain Current - Continuous (T _C = 25°	C)	19.6	А	
	- Continuous (T _C = 100°C)		12.4	А	
I _{DM}	Drain Current - Pulsed	(Note 1)	78.4	А	
V _{GSS}	Gate-Source Voltage		± 25	V	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		230	mJ	
I _{AR}	Avalanche Current (Note 1)		19.6	А	
E _{AR}	Repetitive Avalanche Energy (Note 1)		5.0	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	6.5	V/ns	
P _D	Power Dissipation ($T_A = 25^{\circ}C$) *		2.5	W	
	Power Dissipation ($T_C = 25^{\circ}C$)		50	W	
	- Derate above 25°C		0.4	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C	

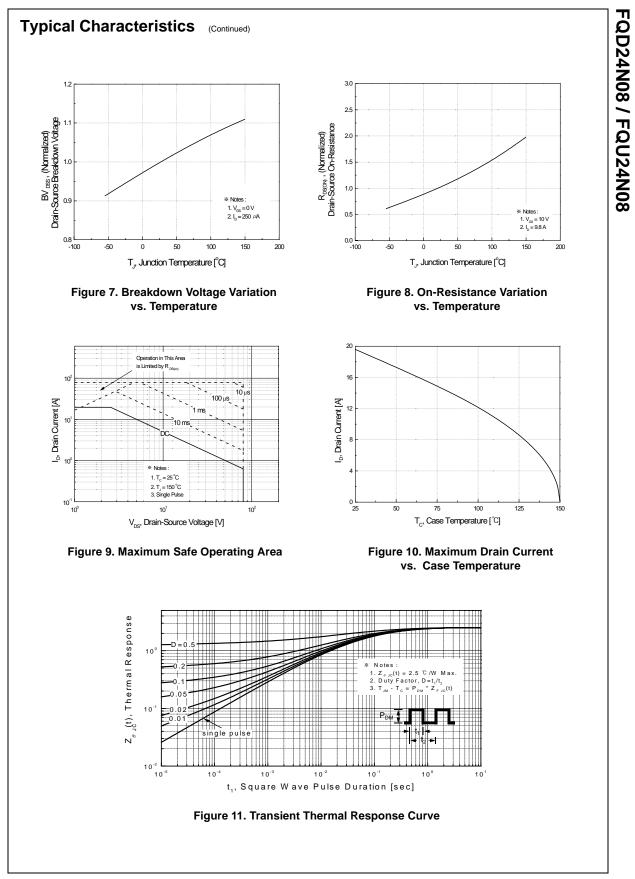
Thermal Characteristics

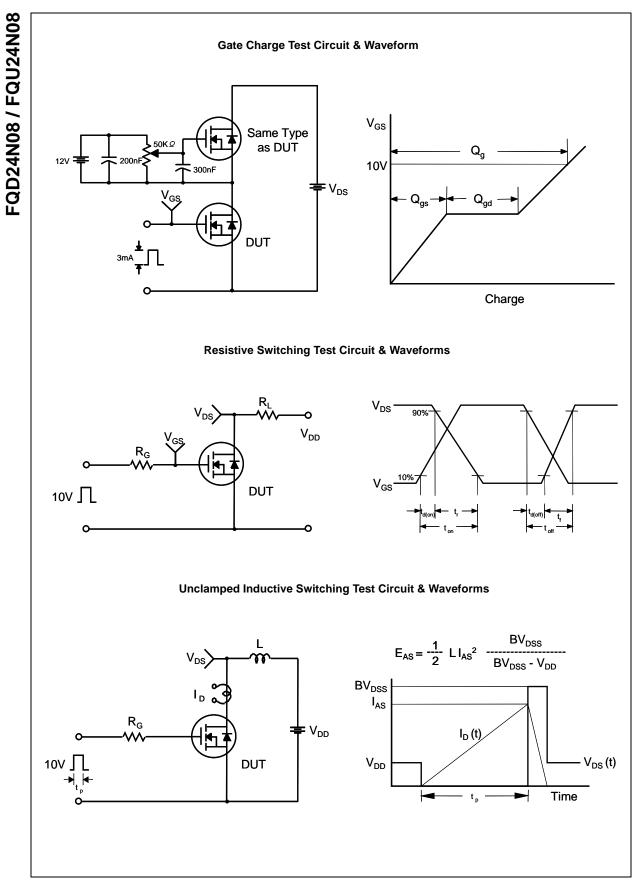
npol	Parameter	Тур	Max	Units
Thermal Res	stance, Junction-to-Case		2.5	°C/W
Thermal Res	stance, Junction-to-Ambient *		50	°C/W
Thermal Res	stance, Junction-to-Ambient		110	°C/W
	stance, Junction-to-Ambient		110	

©2000 Fairchild Semiconductor International

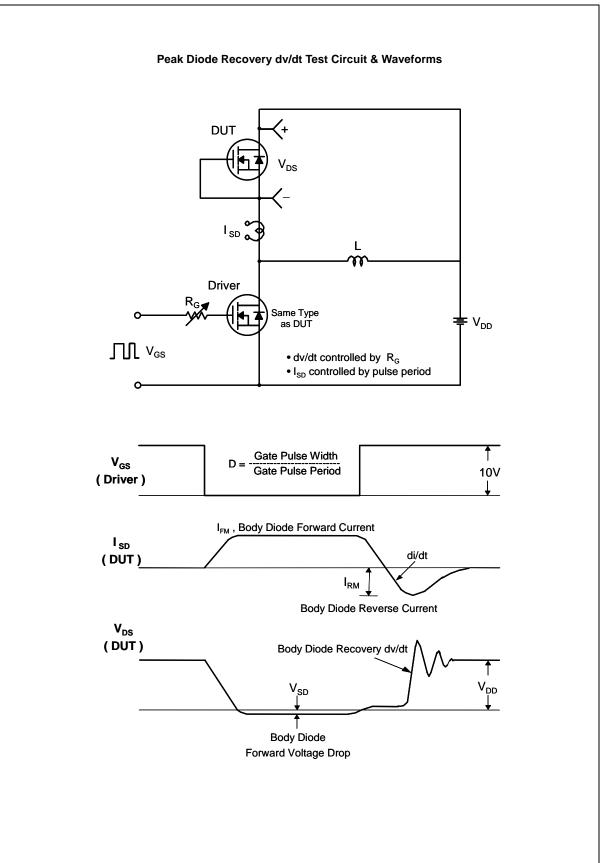
 1 10 100 -100 4.0 0.06 750 270	V V/°C μA μA nA nA V Ω S
 1 100 -100 4.0 0.06 750 270	V/°C μΑ ηΑ ηΑ ηΑ ν Ω S
 1 100 -100 4.0 0.06 750 270	V/°C μΑ ηΑ ηΑ ηΑ ν Ω S
10 100 -100 4.0 0.06 750 270	μΑ nA nA V Ω S
100 -100 4.0 0.06 750 270	nA nA V Ω S
-100 4.0 0.06 750 270	nA V Ω S
4.0 0.06 750 270	V Ω S
0.06 750 270	Ω S pF
0.06 750 270	Ω S pF
 750 270	S pF
750 270	pF
270	· _
270	· _
270	· _
	n⊢
65	pF pF
30	ns
220	ns
70	ns
80	ns
25	nC
	nC
	nC
19.6	A
	A
	V
	ns
	nC
	 19.6 78.4 1.5

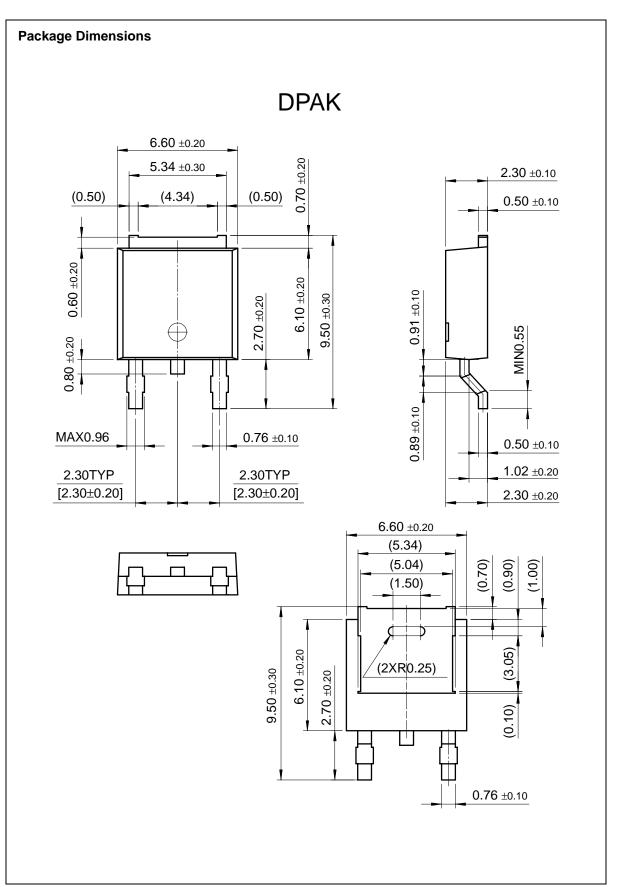


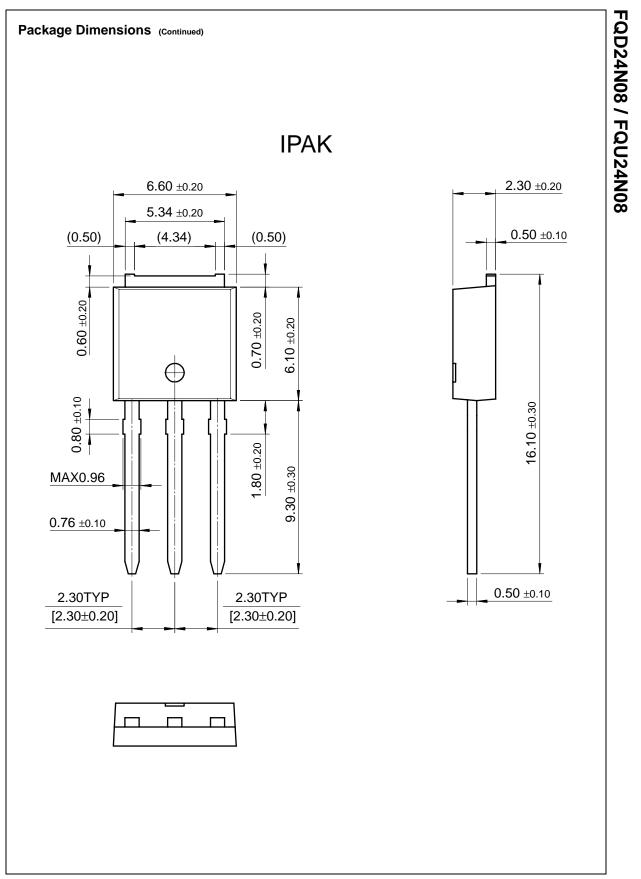




©2000 Fairchild Semiconductor International







TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx [™]	FASTr [™]	QFET [™]	VCX™
Bottomless [™]	GlobalOptoisolator [™]	QS [™]	
CoolFET [™]	GTO [™]	QT Optoelectronics [™]	
CROSSVOLT [™]	HiSeC [™]	Quiet Series [™]	
DOME [™]	ISOPLANAR [™]	SuperSOT [™] -3	
E ² CMOS [™]	MICROWIRE [™]	SuperSOT [™] -6	
EnSigna [™]	OPTOLOGIC [™]	SuperSOT [™] -8	
FACT [™]	OPTOLOGIC [™]	SvncFET [™]	
EnSigna™ FACT™	OPTOLOGIC™ OPTOPLANAR™	•	
FACT Quiet Series™	POP™	TinyLogic™	
FAST [®]	PowerTrench [®]	UHC™	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR INTERNATIONAL.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

		sSEARCH Param	netric Cross Reference
Fairchild Semiconductor		space Prod	uct Folders and Applica
find products	Home >> Find products >>		
Products groups Analog and Mixed	FQD24N08 80V N-Channel QFET		Related Links
Signal Discrete Interface Logic	Contents General description Features Product status/pricing/packaging	Datasheet Download this datasheet	Request samples Dotted line How to order products Dotted line Product Change Notices
Microcontrollers Non-Volatile Memory Optoelectronics	General description	PDF e-mail this datasheet	(PCNs) Dotted line Support Dotted line Distributor and field sales
Markets and applications New products Product selection and	These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.	This page <u>Print version</u>	representatives Dotted line Quality and reliability Dotted line Design tools
parametric search Cross-reference search	This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche		Design tools
technical information buy products	and commutation mode. These devices are well suited for low voltage applications such as high efficiency switching DC/DC converters, and		-
technical support	- DC motor control.		
my Fairchild	- back to top		
company			

- 19.6A, 80V, R $_{DS(on)} = 0.006\Omega$ @V GS = 10 V
- Low gate charge (typical 19 nC)
- Low Crss (typical 50 pF)
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

back to top

Features

Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
FQD24N08TF	Full Production	\$0.56	TO-252(DPAK)	2	TAPE REEL

FQD24N08TM	Full Production	\$0.56	TO-252(DPAK)	2	TAPE REEL	
* 1 000 piece Budgetary Pricing						

1,000 piece Budgetary Pricing

back to top

Home | Find products | Technical information | Buy products | Support | Company | Contact us | Site index | Privacy policy

© Copyright 2002 Fairchild Semiconductor